

# BC488B

## High Current Transistors

### PNP Silicon

#### Features

- Pb-Free Package is Available\*

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	$V_{CEO}$	-60	Vdc
Collector - Base Voltage	$V_{CBO}$	-60	Vdc
Emitter-Base Voltage	$V_{EBO}$	-4.0	Vdc
Collector Current - Continuous	$I_C$	-1.0	Adc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	1.5 12	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

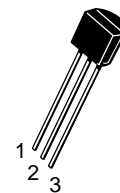
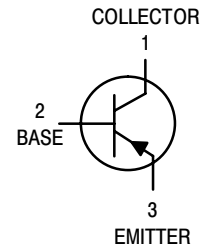
#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$



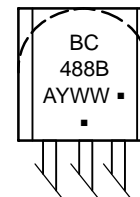
ON Semiconductor®

<http://onsemi.com>



TO-92  
CASE 29  
STYLE 17

#### MARKING DIAGRAM



BC488B = Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
■ = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

Device	Package	Shipping†
BC488BRL1	TO-92	2000/Tape & Reel
BC488BRL1G	TO-92 (Pb-Free)	2000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# BC488B

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector–Emitter Breakdown Voltage (Note 1) (I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	-60	-	-	Vdc
Collector–Base Breakdown Voltage (I <sub>C</sub> = -100 μA, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	-60	-	-	Vdc
Emitter–Base Breakdown Voltage (I <sub>E</sub> = -10 μA, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	-4.0	-	-	Vdc
Collector Cutoff Current (V <sub>CB</sub> = -40 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-	-100	nA

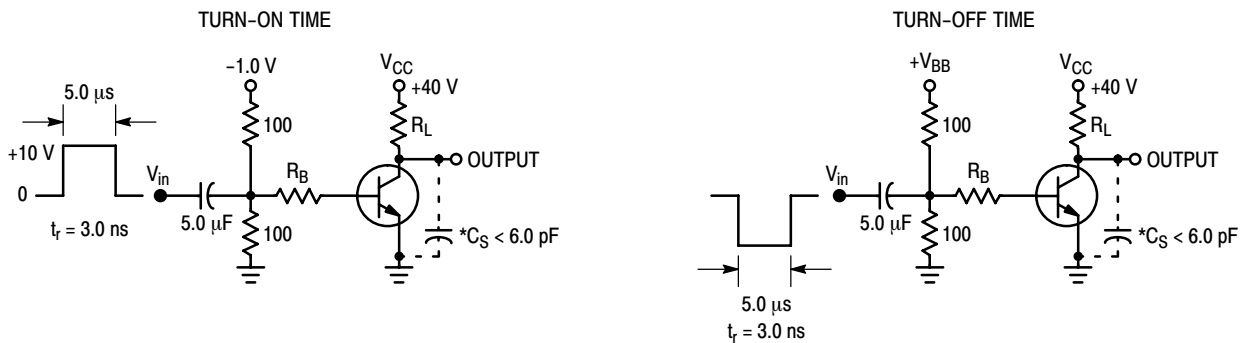
## ON CHARACTERISTICS\*

DC Current Gain (I <sub>C</sub> = -10 mA, V <sub>CE</sub> = -2.0 Vdc) (I <sub>C</sub> = -100 mA, V <sub>CE</sub> = -2.0 Vdc) (I <sub>C</sub> = -1.0 A, V <sub>CE</sub> = -5.0 Vdc)	h <sub>FE</sub>	40 160 15	- 260 -	- 400 -	-
Collector–Emitter Saturation Voltage (I <sub>C</sub> = -500 mA, I <sub>B</sub> = -50 mA) (I <sub>C</sub> = -1.0 A, I <sub>B</sub> = -100 mA)	V <sub>CE(sat)</sub>	- -	-0.25 -0.5	-0.5 -	Vdc
Base–Emitter Saturation Voltage (I <sub>C</sub> = -500 mA, I <sub>B</sub> = -50 mA) (I <sub>C</sub> = -1.0 A, I <sub>B</sub> = -100 mA)	V <sub>BE(sat)</sub>	- -	-0.9 -1.0	-1.2 -	Vdc

## DYNAMIC CHARACTERISTICS

Current–Gain – Bandwidth Product (I <sub>C</sub> = -50 mA, V <sub>CE</sub> = -2.0 Vdc, f = 100 MHz)	f <sub>T</sub>	-	150	-	MHz
Output Capacitance (V <sub>CB</sub> = -10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>ob</sub>	-	9.0	-	pF
Input Capacitance (V <sub>EB</sub> = -0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ib</sub>	-	110	-	pF

1. Pulse Test: Pulse Width = 300 μs, Duty Cycle 2%.



\*Total Shunt Capacitance of Test Jig and Connectors  
For PNP Test Circuits, Reverse All Voltage Polarities

**Figure 1. Switching Time Test Circuits**

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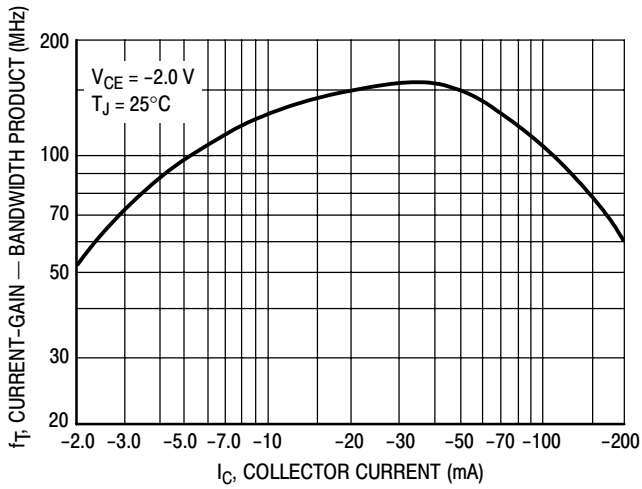


Figure 2. Current-Gain - Bandwidth Product

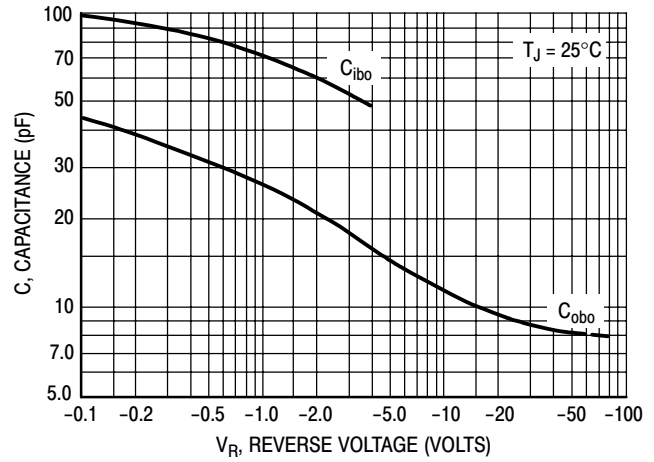


Figure 3. Capacitance

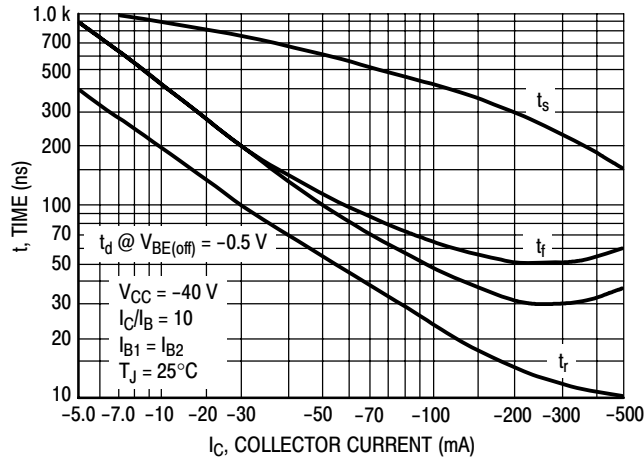


Figure 4. Switching Time

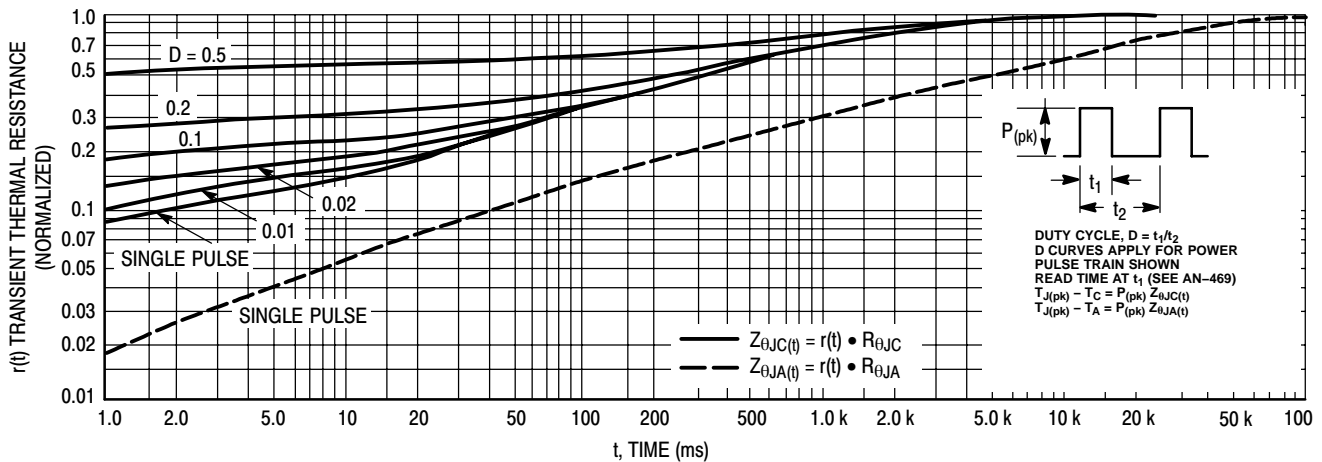


Figure 5. Thermal Response

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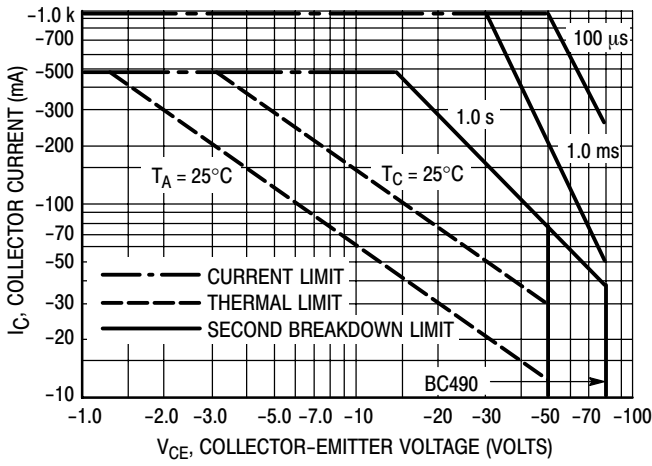


Figure 6. Active Region, Safe Operating Area

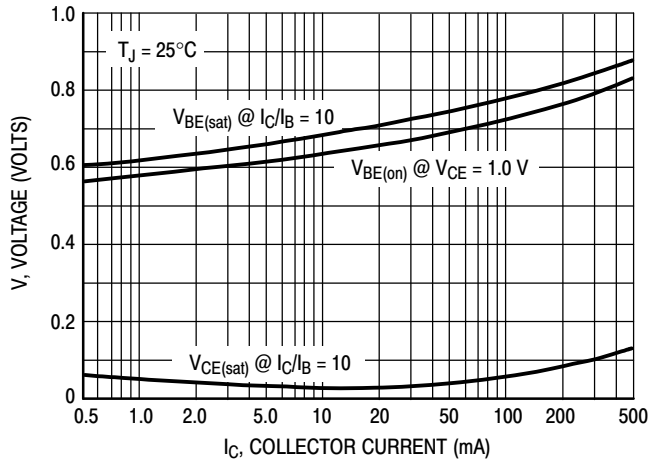


Figure 7. "On" Voltages

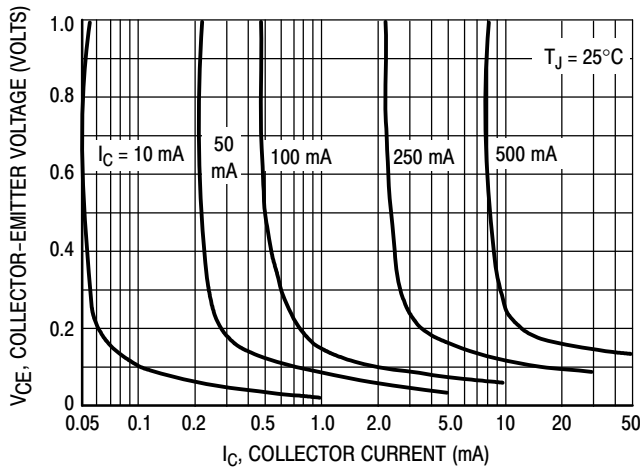


Figure 8. Collector Saturation Region

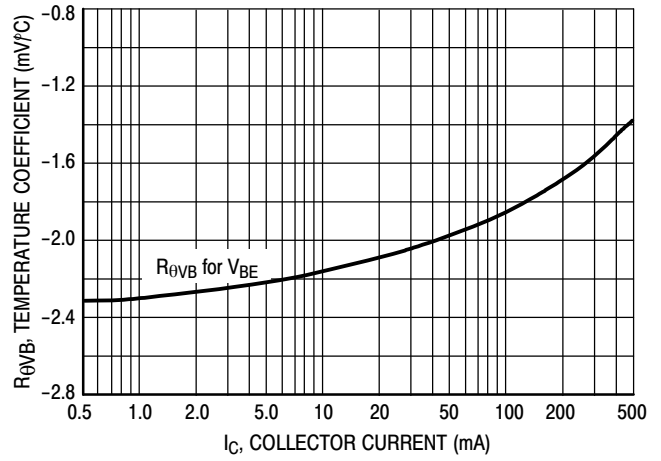


Figure 9. Base-Emitter Temperature Coefficient

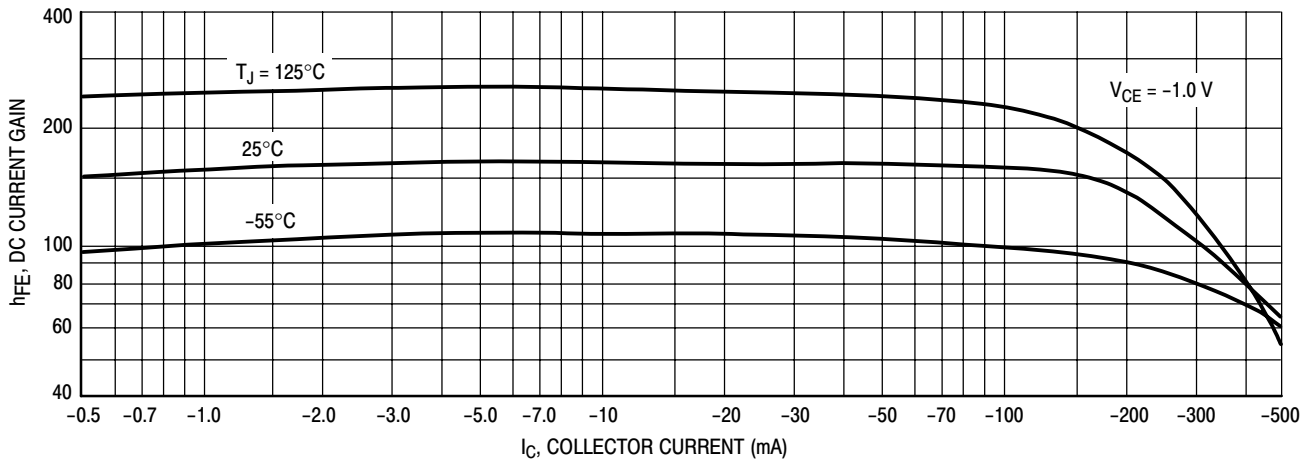


Figure 10. DC Current Gain

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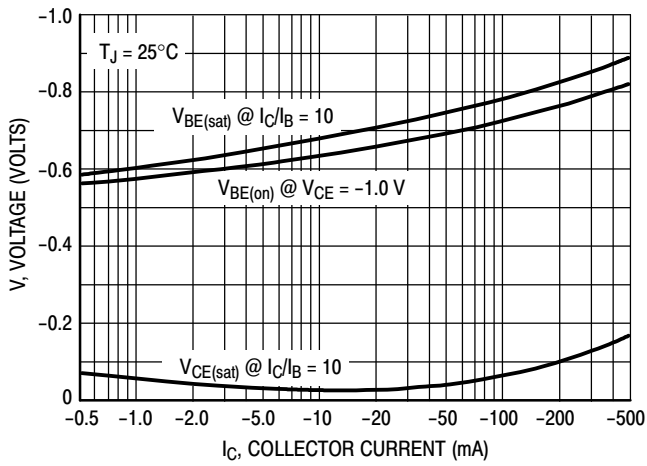


Figure 11. "On" Voltages

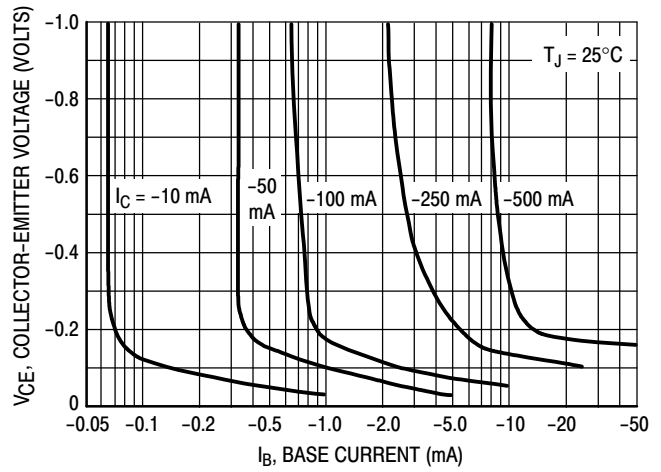


Figure 12. Collector Saturation Region

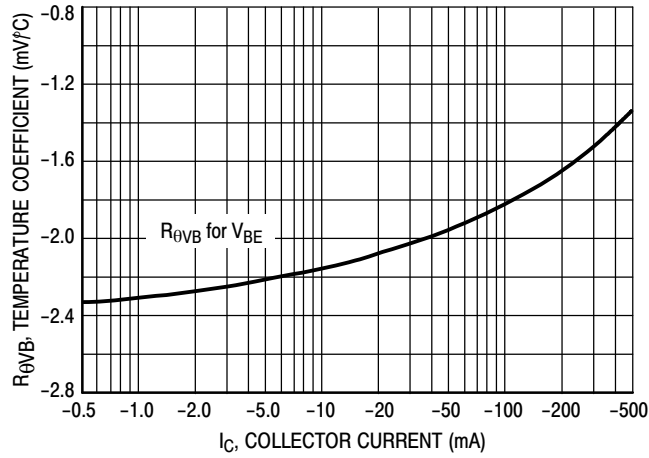
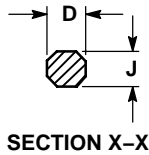
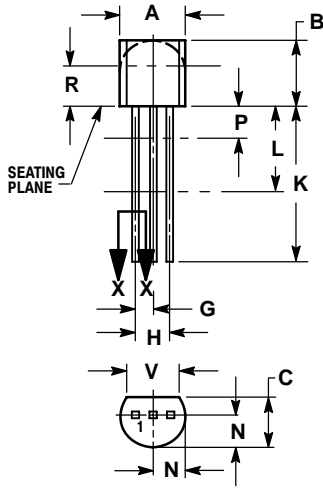


Figure 13. Base-Emitter Temperature Coefficient

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## PACKAGE DIMENSIONS

TO-92  
(TO-226)  
CASE 29-11  
ISSUE AL



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

**STYLE 17:**

1. COLLECTOR
2. BASE
3. EMITTER

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